

FUJITSU

J-FET INPUT OPERATIONAL AMPLIFIER

MB47082

1

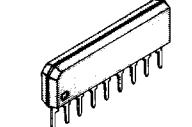
Apr. 1989
Edition 1.0

J-FET INPUT OPERATIONAL AMPLIFIER

The Fujitsu MB47082 is designed for a dual operational amplifier with P channel-typed J-FET used at the Input stage. Its slew rate is faster (more than one figure) comparing with the standard operational amplifier and also its band width is wide because of its high input impedance characteristics and well-built transmission conductance at the input stage comparing with the bipolar transistor.

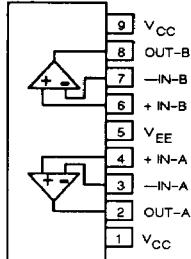
The MB47082 is suitable for a D/A converter and a Sample & Hold circuit that need to cover from a small signal amplification to a fast and large signal change.

- Compatible with TL082
- Wide operating power supply voltage: $\pm 5V$ to $\pm 15V$
- Fast slew rate : $13V/\mu s$ typ.
- Low Input bias current : $30pA$ typ.
- Wide frequency bandwidth : $3MHz$ typ.
- On-chip internal frequency compensation
- Low noise

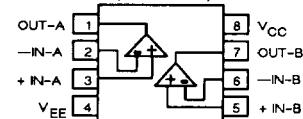
PLASTIC PACKAGE
SIP-09P-M01PLASTIC PACKAGE
DIP-08P-M01PLASTIC PACKAGE
FPT-08P-M01

PIN ASSIGNMENT

SIP: (FRONT VIEW)



DIP,FPT: (TOP VIEW)



ABSOLUTE MAXIMUM RATINGS (see NOTE) (TA=25°C)

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	+18	V
	V _{EE}	-18	V
Differential Input Voltage	V _{ID}	± 30	V
Common-mode Input Voltage	V _I	± 15	V
Power Dissipation	P _D	350 (TA $\leq 55^{\circ}C$)	mW
Operating Temperature	T _A	-20 to 75	°C
Storage Temperature	T _{STG}	-55 to 125	°C

NOTE: Permanent device damage may occur if the above Absolute Maximum Ratings are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

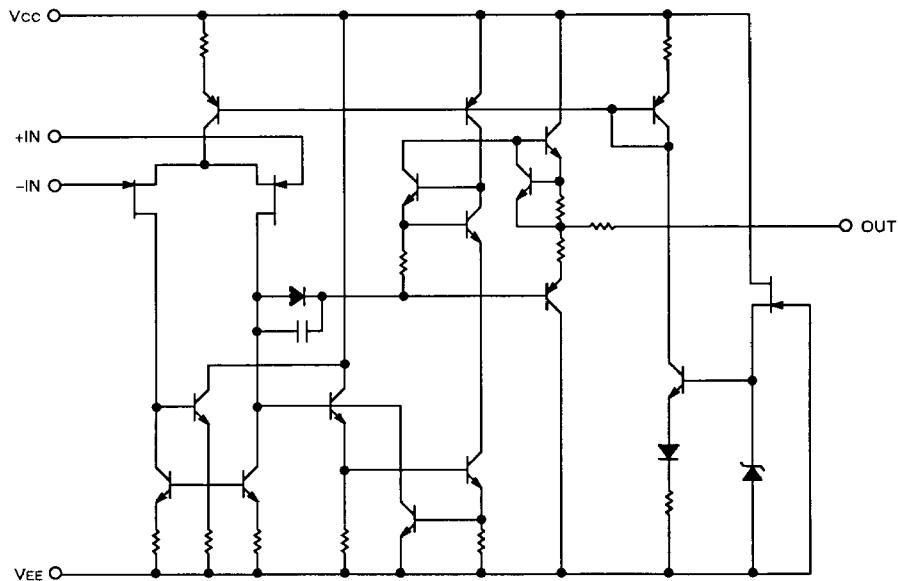
This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

FUJITSU

MB47082

1

Fig. 1 — MB47082 EQUIVALENT CIRCUIT



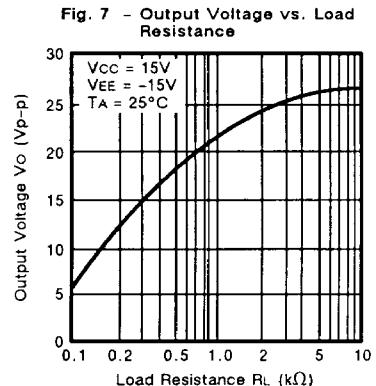
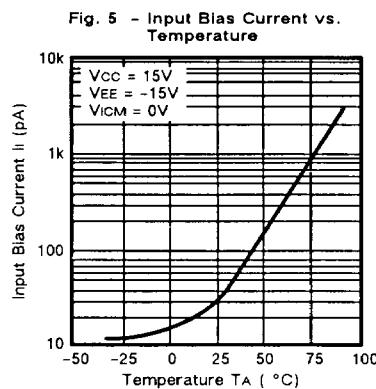
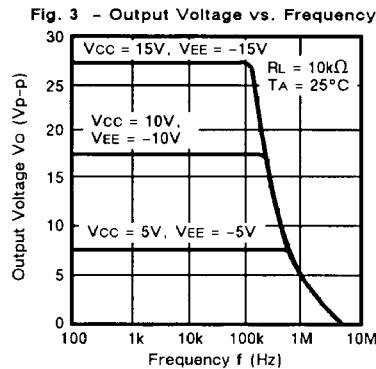
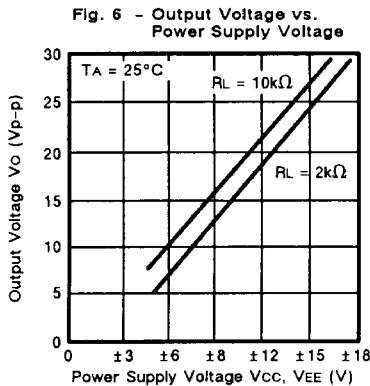
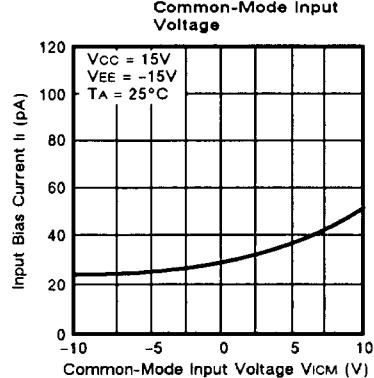
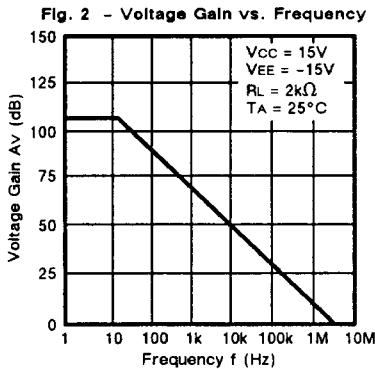
RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value	Unit
Power Supply Voltage	V _{CC} , V _{EE}	±5 to ±15	V
Operating Temperature	T _A	-20 to +75	°C

(T_A =25°C, V_{CC}=15V, V_{EE} =-15V)

Parameter	Symbol	Condition	Value			Unit
			Min	Typ	Max	
Input Offset Voltage	V _{IO}	R _S ≤50Ω		5.0	15.0	mA
Input Offset Current	I _{IO}			5	200	pA
Input Bias Current	I _I			30	400	pA
Common-mode Input Voltage	V _{CIM}		±10			V
Common-mode Rejection Ratio	CMRR	R _S ≤10kΩ	70	86		dB
Power Supply Voltage Rejection Ratio	SVRR	R _S ≤10kΩ	70	86		dB
Voltage Gain	A _V	R _L =2kΩ	25	200		V/mV
Power Supply Current	I _{CC}			3.5	5.6	mA
Maximum Output Voltage	V _{OM}	R _L ≥18kΩ	±12	±13.5		V
		R _L ≥2kΩ	±10	±12		V
Output Current	I _{SOURCE}	V _O =V _{EE}		-25	-10	mA
	I _{SINK}	V _O =V _{CC}	25	40		mA
Frequency Bandwidth	BW	R _L =2kΩ		3.0		MHz
Slew Rate	SR	R _L =2kΩ, C=100pF, A _V =1		13		V/μs
Channel Separation	CS	f=1kHz		120		dB
Equivalent Input Noise Voltage	V _{NI}	f=1kHz, R _S =100Ω		25		nV/√Hz

ELECTRICAL CHARACTERISTICS CURVES



ELECTRICAL CHARACTERISTICS CURVES (Continued)

Fig. 8 – Input Noise Voltage vs. Frequency

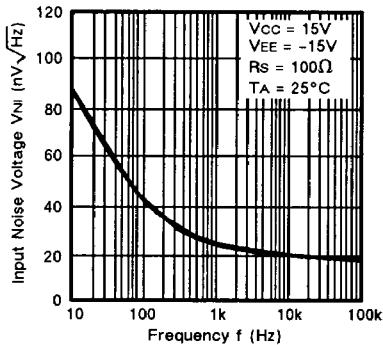


Fig. 10 – Power Supply Current vs. Power Supply Voltage

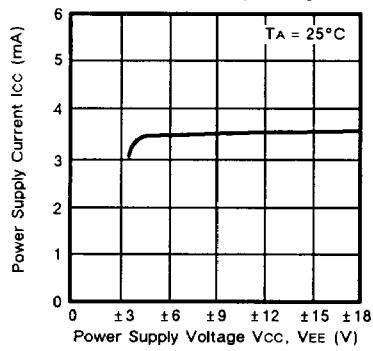


Fig. 9 – Pulse Response

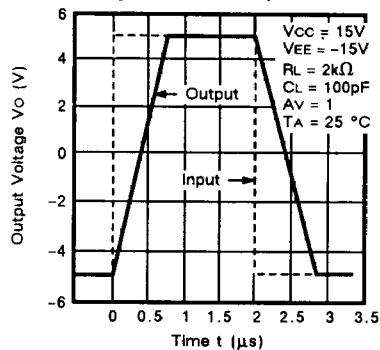
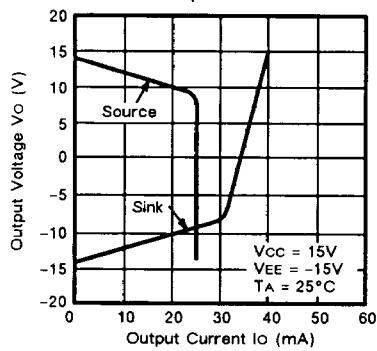


Fig. 11 – Output Voltage vs. Output Current

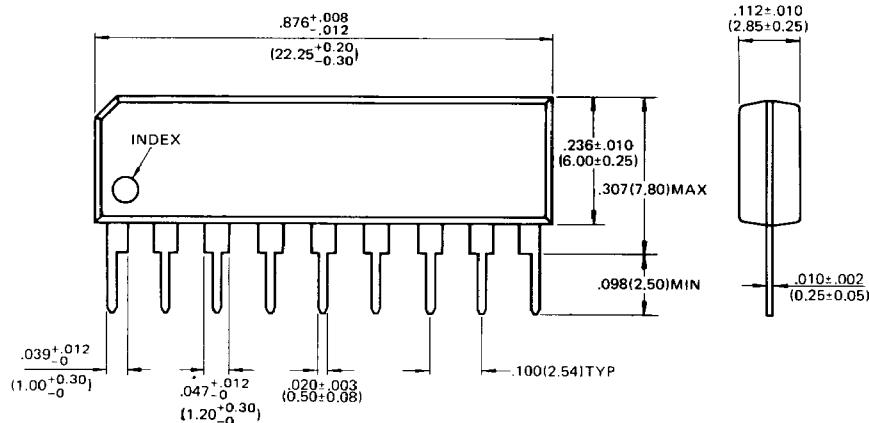


FUJITSU

MB47082

1

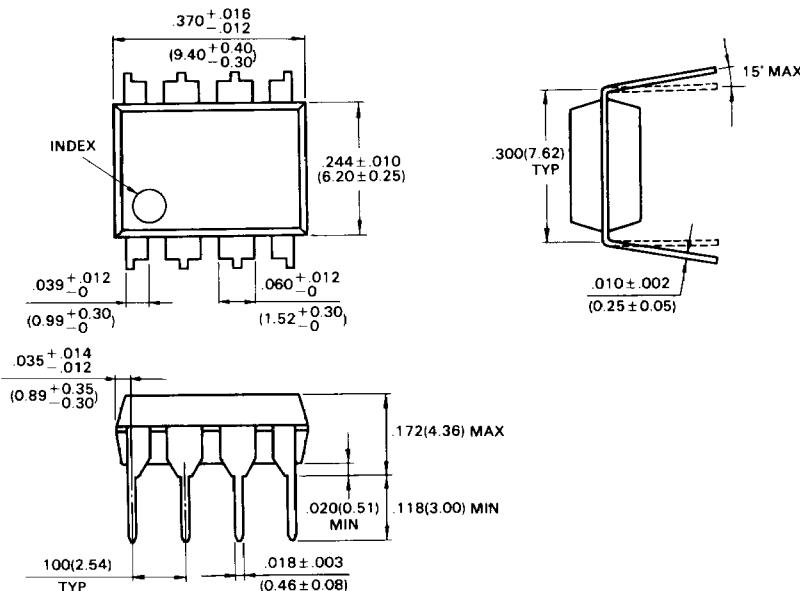
**9-LEAD PLASTIC SINGLE-IN-LINE PACKAGE
(CASE No.: SIP-09P-M01)**



© 1988 FUJITSU LIMITED S090025-3C

Dimensions in
inches (millimeters)

8-LEAD PLASTIC DUAL-IN-LINE PACKAGE
(CASE No.: DIP-08P-M01)



Dimensions in
inches (millimeters)

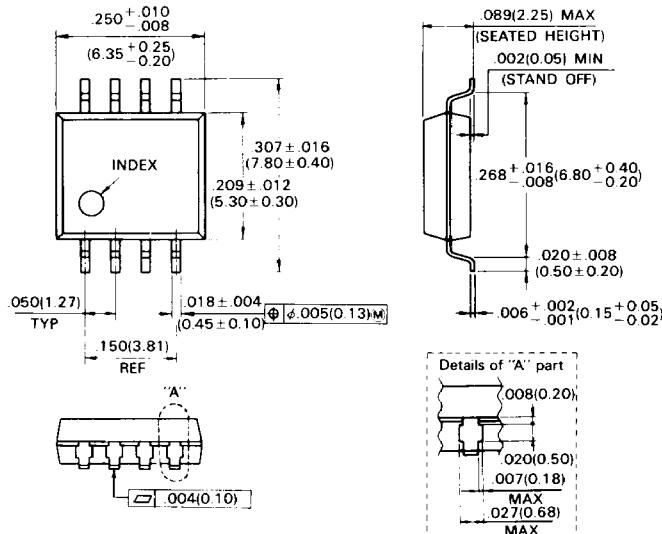
© 1988 FUJITSU LIMITED D08006S-2C

FUJITSU

MB47082

1

**8-LEAD PLASTIC FLAT PACKAGE
(CASE No.: FPT-08P-M01)**



©1988 FUJITSU LIMITED F08002S-3C

Dimensions in
inches (millimeters)